

9/12/2013



**PRODUCT RELIABILITY REPORT
FOR**

MAX31740

Maxim Integrated

**14460 Maxim Dr.
Dallas, TX 75244**

Approved by:

**Don Lipps
Manager, Reliability Engineering**

Conclusion:

The following qualification successfully meets the quality and reliability standards required of all Maxim Integrated products:

MAX31740

In addition, Maxim Integrated's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at <http://www.maximintegrated.com/qa/reliability/monitor>.

Device Description:

A description of this device can be found in the product data sheet. You can find the product data sheet at <http://www.maximintegrated.com/search/parts.mvp>.

Reliability Derating:

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

$$AfT = \exp((Ea/k) * (1/Tu - 1/Ts)) = tu/ts$$

AfT = Acceleration factor due to Temperature
tu = Time at use temperature (e.g. 55°C)
ts = Time at stress temperature (e.g. 125°C)
k = Boltzmann's Constant (8.617 x 10⁻⁵ eV/°K)
Tu = Temperature at Use (°K)
Ts = Temperature at Stress (°K)
Ea = Activation Energy (e.g. 0.7 eV)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7eV will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

$$AfV = \exp(B * (Vs - Vu))$$

AfV = Acceleration factor due to Voltage
Vs = Stress Voltage (e.g. 7.0 volts)
Vu = Maximum Operating Voltage (e.g. 5.5 volts)
B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

$$Fr = X / (ts * AfV * AfT * N * 2)$$

X = Chi-Sq statistical upper limit
N = Life test sample size

Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

$$\text{MTTF} = 1/\text{Fr}$$

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process is:

FAILURE RATE:	MTTF (YRS):	21159	FITS:	5.4
	DEVICE HOURS:	169834216	FAILS:	0

Only data from Operating Life or similar stresses are used for this calculation.

The parameters used to calculate this failure rate are as follows:

Cf: 60%	Ea: 0.7	B: 0	Tu: 25 °C	Vu: 5.5 Volts
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The reliability data follows. At the start of this data is the device information. The next section is the detailed reliability data for each stress. The reliability data section includes the latest data available and may contain some generic data. **Bold** Product Number denotes specific product data.

Device Information:

Process:	Maxim X3 Fab, S18, 3V & 5V CMOS, 4 metals
Passivation:	SiN / SiO2
Die Size:	46 x 37
Number of Transistors:	7133
Interconnect:	Aluminum / 0.5% Copper
Gate Oxide Thickness:	140Å

ESD HBM

DESCRIPTION	DATE CODE/PRODUCT/LOT	CONDITION	READPOIN	QTY	FAILS	FA#
ESD SENSITIVITY	1311 MAX31740	XJ332800AB JESD22-A114 HBM 500 VOLTS	1	PUL'S	5	0
ESD SENSITIVITY	1311 MAX31740	XJ332800AB JESD22-A114 HBM 1000 VOLTS	1	PUL'S	5	0
ESD SENSITIVITY	1311 MAX31740	XJ332800AB JESD22-A114 HBM 1500 VOLTS	1	PUL'S	5	0
ESD SENSITIVITY	1311 MAX31740	XJ332800AB JESD22-A114 HBM 2000 VOLTS	1	PUL'S	5	0
ESD SENSITIVITY	1311 MAX31740	XJ332800AB JESD22-A114 HBM 2500 VOLTS	1	PUL'S	5	0
Total:					0	

LATCH-UP

DESCRIPTION	DATE CODE/PRODUCT/LOT	CONDITION	READPOIN	QTY	FAILS	FA#
LATCH-UP I	1311 MAX31740	XJ332800AB JESD78A, I-TEST 25C 100mA		6	0	
LATCH-UP I	1311 MAX31740	XJ332800AB JESD78A, I-TEST 25C 250mA		6	0	
LATCH-UP V	1311 MAX31740	XJ332800AB JESD78A, V-SUPPLY TEST 25C		6	0	
Total:					0	

DESCRIPTION	DATE	CODE/PRODUCT/LOT	CONDITION	READPOIN	QTY	FAILS	FA#
HIGH TEMP OP LIFE	1003	MAX17042	QJ000200DA 125C, 5.5 VOLTS	192 HRS	45	0	
HIGH TEMP OP LIFE	1018	DS28E10	QH000900A 125C, 3.6 VOLTS	192 HRS	45	0	
HIGH TEMP OP LIFE	1134	MAX17048	ZJ213800AB 125C, 5.0 VOLTS	192 HRS	77	0	
HIGH TEMP OP LIFE	1240	MAX31790	ZX330900AB 125C, 5.5 VOLTS	192 HRS	80	0	
HIGH TEMP OP LIFE	1302	MAX17048	ZJ386023AB 125C, 5.0 VOLTS	192 HRS	77	0	
HIGH TEMP OP LIFE	1311	MAX31740	XJ332800AB 125C, 5.5 VOLTS	192 HRS	80	0	
HIGH TEMP OP LIFE	1312	MAX31790	ZX330900AC 125C, 5.5 VOLTS	1000 HRS	80	0	
HIGH TEMP OP LIFE	1319	DS2484	ZJ332803AD 125C, 5.25 VOLTS	500 HRS	45	0	
Total:						0	
FAILURE RATE:	MTTF (YRS):		21159	FITS:	5.4		
	DEVICE HOURS:		169834216	FAILS:	0		

Cumulative monitor data for the S18 Process results in a FIT Rate of 0.05 @ 25C and 0.93 @ 55C (0.8 eV, 60% UCL).